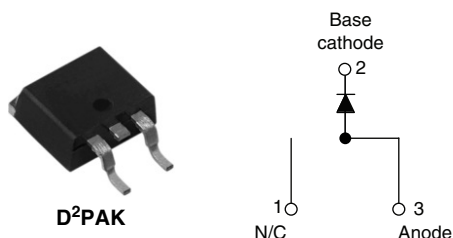


Schottky Rectifier, 20 A



FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified for Q101 level

DESCRIPTION

The 20TQ... Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

PRODUCT SUMMARY

$I_{F(AV)}$	20 A
V_R	35 to 45 V

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	20	A
V_{RRM}	Range	35 to 45	V
I_{FSM}	$t_p = 5 \mu s$ sine	1800	A
V_F	20 Apk, $T_J = 125^\circ C$	0.51	V
T_J	Range	- 55 to 150	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	20TQ035S	20TQ040S	20TQ045S	UNITS
Maximum DC reverse voltage	V_R	35	40	45	V
Maximum working peak reverse voltage	V_{RWM}				

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	$I_{F(AV)}$	50 % duty cycle at $T_C = 116\text{ }^{\circ}\text{C}$, rectangular waveform		20	A
Maximum peak one cycle non-repetitive surge current See fig. 7	I_{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	1800	
		10 ms sine or 6 ms rect. pulse		400	
Non-repetitive avalanche energy	E_{AS}	$T_J = 25\text{ }^{\circ}\text{C}$, $I_{AS} = 4\text{ A}$, $L = 3.40\text{ mH}$		27	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		4	A

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum forward voltage drop See fig. 1	$V_{FM}^{(1)}$	20 A	$T_J = 25\text{ }^{\circ}\text{C}$	0.57	V	
		40 A		0.73		
		20 A	$T_J = 125\text{ }^{\circ}\text{C}$	0.51		0.67
		40 A				
Maximum reverse leakage current See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^{\circ}\text{C}$	$V_R = \text{Rated } V_R$	2.7	mA	
		$T_J = 125\text{ }^{\circ}\text{C}$		105		
Maximum junction capacitance	C_T	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^{\circ}\text{C}$		1400	pF	
Typical series inductance	L_S	Measured lead to lead 5 mm from package body		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/ μ s	

Note(1) Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.50	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style D ² PAK	20TQ035S	
			20TQ040S	
			20TQ045S	

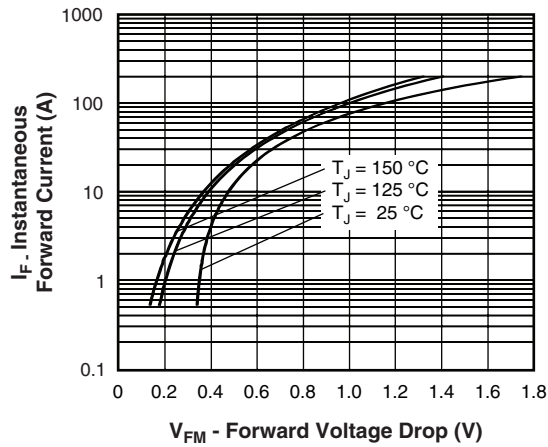


Fig. 1 - Maximum Forward Voltage Drop Characteristics

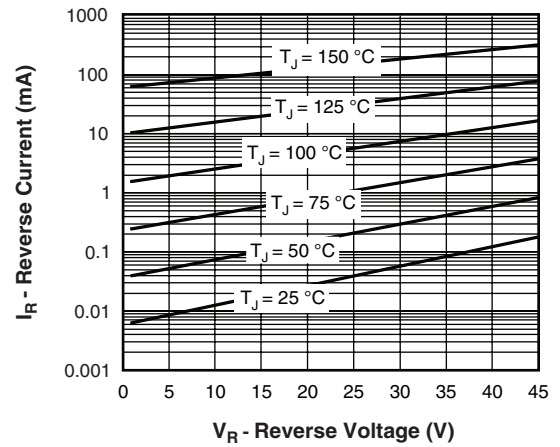


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

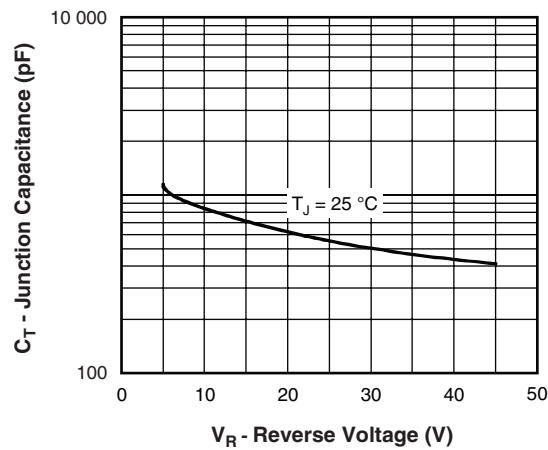
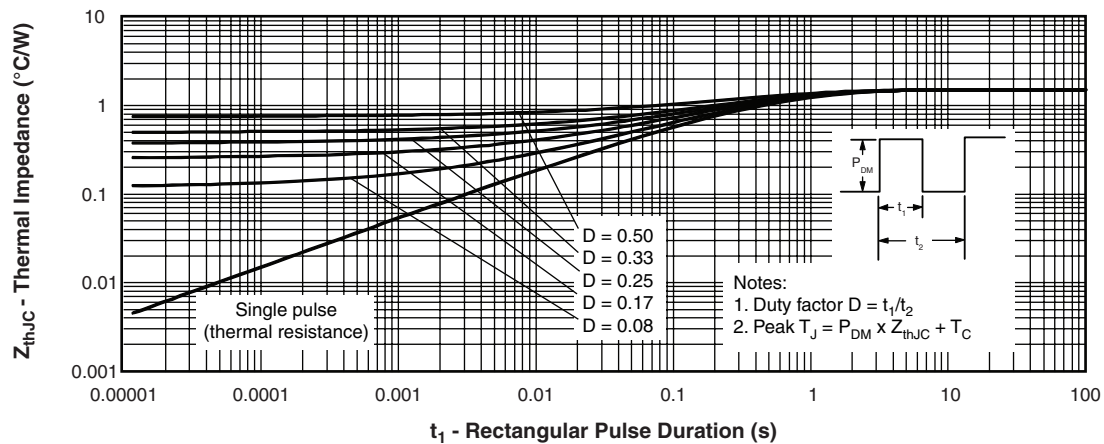


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

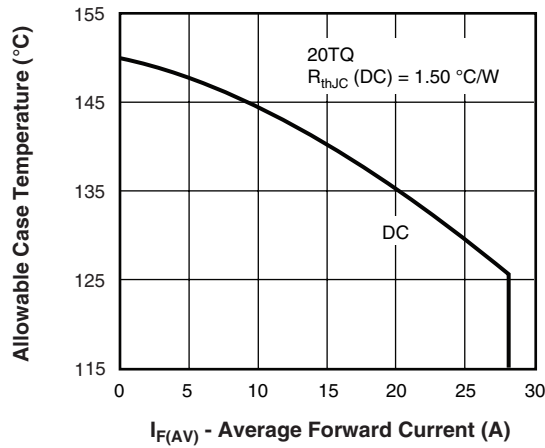


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

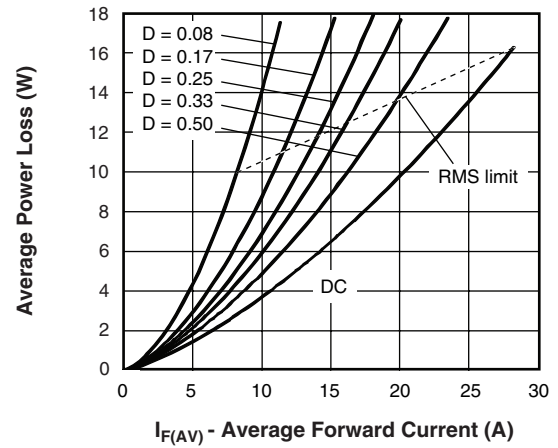


Fig. 6 - Forward Power Loss Characteristics

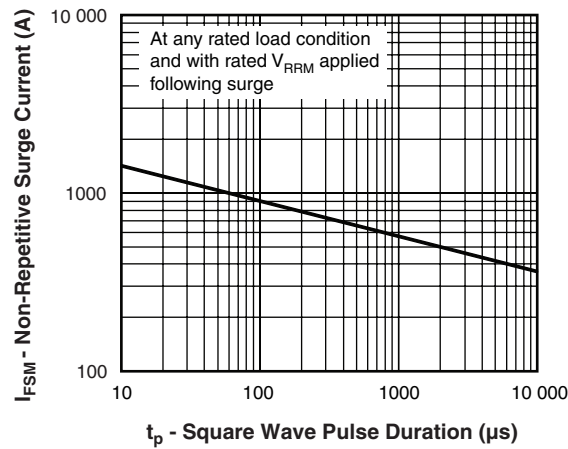


Fig. 7 - Maximum Non-Repetitive Surge Current

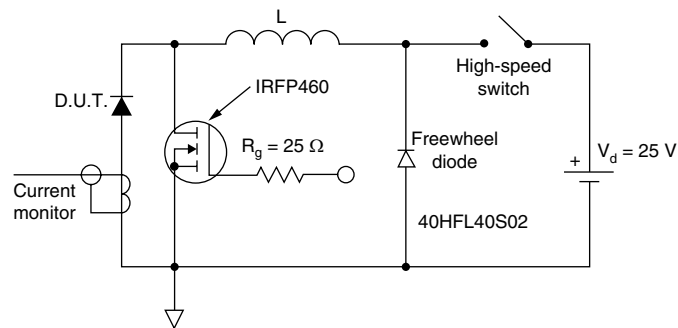


Fig. 8 - Unclamped Inductive Test Circuit

**ORDERING INFORMATION TABLE**

Device code	20	T	Q	045	S	TRL	-
	1	2	3	4	5	6	7
1	-	Current rating (20 A)					
2	-	Package:					
		T = TO-220					
3	-	Schottky "Q" series					
4	-	Voltage ratings					
5	-	• S = D ² PAK					
6	-	• None = Tube (50 pieces)					
		• TRL = Tape and reel (left oriented)					
		• TRR = Tape and reel (right oriented)					
7	-	• None = Standard production					
		• PbF = Lead (Pb)-free					

035 = 35 V
040 = 40 V
045 = 45 V

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95014
Part marking information	http://www.vishay.com/doc?95008
Packaging information	http://www.vishay.com/doc?95032



Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.